

LT251A

GaAs Hall IC for Noncontact Switch
(Unidirectional magnetic field-type)

■ Features

- Operation by small magnet due to high sensitivity operating point < 30mT
- Combining a GaAs Hall device and an IC in a compact package (2.9 X 1.5 X 1.1mm)
- Wide operation temperature range obtained by GaAs Hall device (-20 to +125°C)
- Long life time due to noncontact-type

■ Applications

- FDD
- HDD
- Water meter
- Car stereo
- Micro switch, etc.

■ Absolute Maximum Ratings

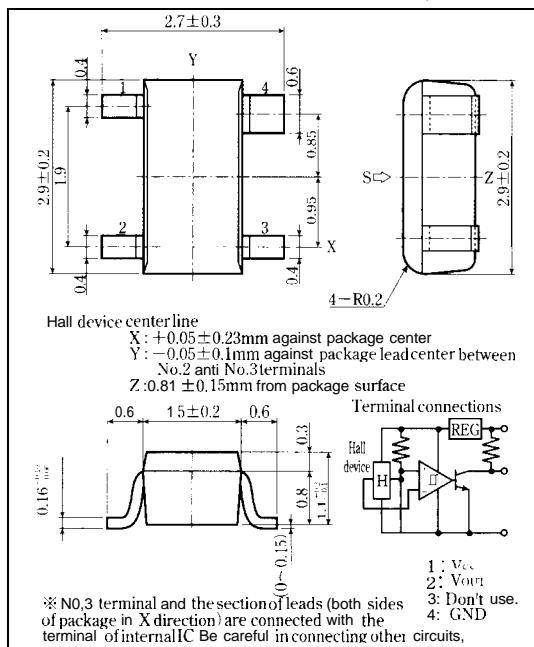
(Ta=25°C)

Parameter	Symbol	Rating	Unit
Supply voltage	Vcc	18	v
Output voltage	Vout	18	V
Output current	Io	5	mA
Power dissipation	Pd	100	mW
Operating temperature	Topr	-20 to +125	°C
Storage temperature	Tstg	-55 to +150	°C
Soldering temperature ^{*1}	Tsol	260	°C

*1 Soldering time within 10 seconds

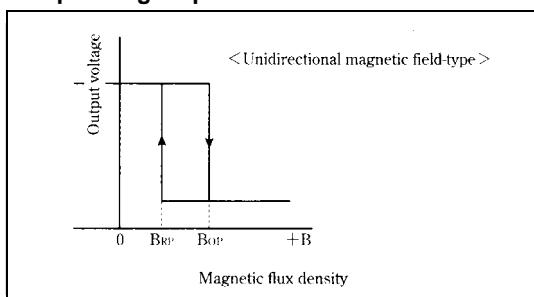
■ Outline Dimensions

(Unit : mm)



As for dimensions of tape-packaged products, refer to page 44.

■ Operating Explanation



■ Electrical Characteristics

(Ta=25°C)

Parameter	Symbol	Conditions	MIN.	m	MAX.	Unit
Operating magnetic flux density	Bop	Vcc = 16V	11	—	30	mT
Hysteresis breadth	Brp		10	—	29	mT
operating voltage	Vcc		1	—	5	mT
Supply current	Icc	Vcc = 16V, B ≤ 10mT	—	—	10.5	mA
Low level output voltage	V(1)	Vcc = 16V, Io = 4mA, B ≥ 30mT	—	—	0.4	v
High level output voltage	Voh	Vcc = 16V, Io = -100 μA, B ≤ 10mT	13.9	—	—	V
Output short circuit current	Ios	Vcc = 16V	-1.55	—	-0.80	mA
Operating point temperature drift	ΔBop	Vcc = 16V, Ta = -5°C to +60°C	—	2.0	4.5	mT
		Vcc = 16V, Ta = -20°C to +80°C	—	2.5	8.0	mT

Fig. 1 Operating Magnetic Flux Density vs. Supply Voltage

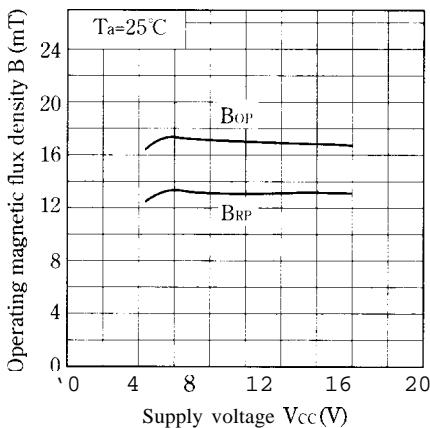


Fig. 2 Operating Magnetic Flux Density vs. Ambient Temperature

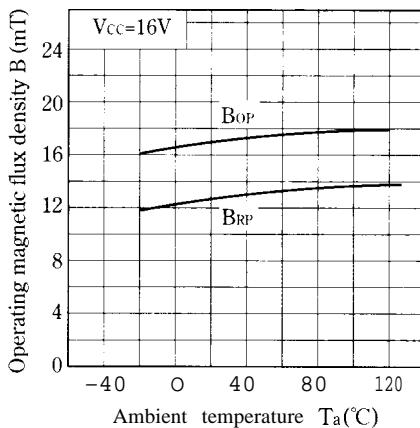


Fig. 3 Supply Current vs. Supply Voltage

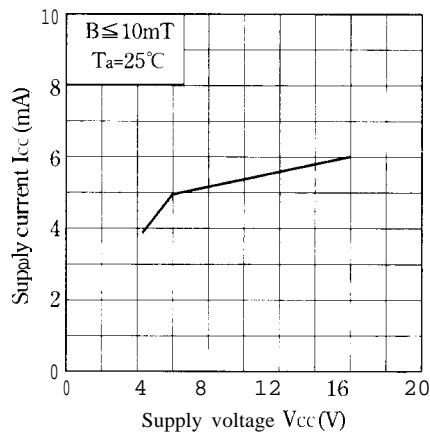


Fig. 4 Supply Current vs. Ambient Temperature

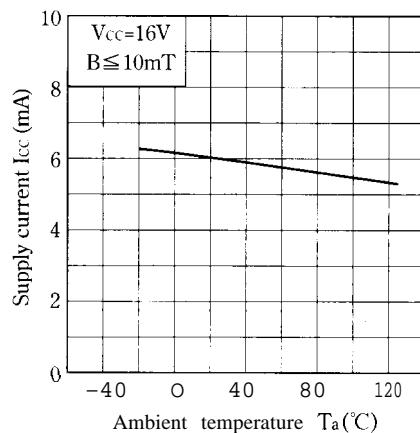


Fig. 5 Low Level Output Voltage vs. Output Current

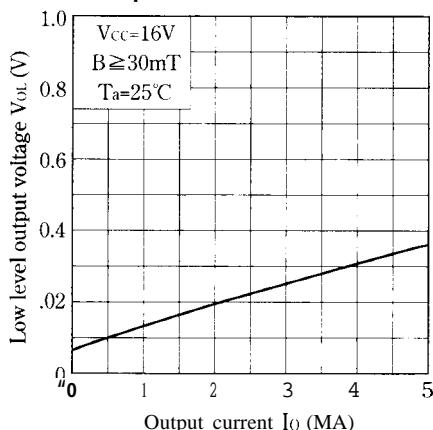


Fig. 6 Low Level Output Voltage vs. Ambient Temperature

